

**SKiiP® 2**

## 2-pack - integrated intelligent Power System

### Power section

#### SKiiP 802GB061-259CTV

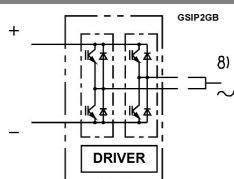
### Features

- SKiiP technology inside
- Low loss IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 2 power section)

- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 8) AC connection busbars must be connected by the user; copper busbars available on request

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$	Operating DC link voltage	600	V
$V_{CC}^{1)}$		400	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_s = 25\text{ (70) °C}$	800 (600)	A
<b>Inverse diode</b>			
$I_F = -I_C$	$T_s = 25\text{ (70) °C}$	800 (600)	A
$I_{FSM}$	$T_j = 150\text{ °C}$ , $t_p = 10\text{ ms}$ ; sin.	8000	A
$I^2t$ (Diode)	Diode, $T_j = 150\text{ °C}$ , 10 ms	320	kA <sup>2</sup> s
$T_j, (T_{stg})$		- 40 (- 25) ... + 150 (125)	°C
$V_{isol}$	AC, 1 min. (mainterminals to heat sink)	2500	V

Characteristics		$T_s = 25\text{ °C}$ unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
$V_{CESat}$	$I_C = 800\text{ A}$ , $T_j = 25\text{ (125) °C}$		2,3 (2,6)	2,6	V
$V_{CEO}$	$T_j = 25\text{ (125) °C}$		0,8 (0,7)	1 (0,9)	V
$r_{CE}$	$T_j = 25\text{ (125) °C}$		1,9 (2,4)	2 (2,5)	mΩ
$I_{CES}$	$V_{GE} = 0\text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25\text{ (125) °C}$		(40)	0,8	mA
$E_{on} + E_{off}$	$I_C = 800\text{ A}$ , $V_{CC} = 300\text{ V}$ $T_j = 125\text{ °C}$ , $V_{CC} = 400\text{ V}$			72	mJ
				105	mJ
$R_{CC'} + EE'$	terminal chip, $T_j = 125\text{ °C}$		0,25		mΩ
$L_{CE}$	top, bottom		7,5		nH
$C_{CHC}$	per phase, AC-side		1,6		nF
<b>Inverse diode</b>					
$V_F = V_{EC}$	$I_F = 800\text{ A}$ , $T_j = 25\text{ (125) °C}$		1,5 (1,5)	1,8	V
$V_{TO}$	$T_j = 25\text{ (125) °C}$		0,8 (0,6)	1 (0,8)	V
$r_T$	$T_j = 25\text{ (125) °C}$		0,9 (1,1)	0,9 (1,2)	mΩ
$E_{rr}$	$I_C = 800\text{ A}$ , $V_{CC} = 300\text{ V}$ $T_j = 125\text{ °C}$ , $V_{CC} = 400\text{ V}$			26	mJ
				30	mJ
<b>Mechanical data</b>					
$M_{dc}$	DC terminals, SI Units	6		8	Nm
$M_{ac}$	AC terminals, SI Units	13		15	Nm
w	SKiiP® 2 System w/o heat sink		1,9		kg
w	heat sink		4,7		kg
<b>Thermal characteristics (P16 heat sink; 310 m<sup>3</sup>/h); " r " reference to temperature sensor</b>					
$R_{th(j-s)I}$	per IGBT			0,056	K/W
$R_{th(j-s)D}$	per diode			0,1	K/W
$R_{th(s-a)}$	per module			0,043	K/W
$Z_{th}$	$R_i$ (mK/W) (max. values)	tau <sub>i</sub> (s)			
		1	2	3	4
$Z_{th(j-r)I}$		6	43	7	1
$Z_{th(j-r)D}$		11	77	12	0,13
$Z_{th(r-a)}$		13,9	18,9	6,6	0,001
				3,6	0,13
				262	0,001
				50	5
					0,02



Case S 2

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SKiiP® 2

2-pack - integrated intelligent Power System

2-pack integrated gate driver

SKiiP 802GB061-259CTV

### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP® 2 gate driver)

Absolute Maximum Ratings			
Symbol	Conditions	Values	Units
$V_{S1}$	stabilized 15 V power supply	18	V
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_{iH}$	input signal voltage (high)	15 + 0,3	V
dv/dt	secondary to primary side	75	kV/μs
$V_{isolIO}$	input / output (AC, r.m.s., 2s )	2500	Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s )	1500	Vac
$f_{max}$	switching frequency	20	kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 25 ... + 85	°C

Characteristics				( $T_a = 25\text{ °C}$ )	
Symbol	Conditions	min.	typ.	max.	Units
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
$I_{S1}$	$V_{S1} = 15\text{ V}$	$210+390 \cdot f/f_{max} + 1,3 \cdot (I_{AC}/A)$			mA
$I_{S2}$	$V_{S2} = 24\text{ V}$	$160+290 \cdot f/f_{max} + 1,0 \cdot (I_{AC}/A)$			mA
$V_{iT+}$	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)	5,4			V
$R_{IN}$	input resistance	10			kΩ
$t_{d(on)IO}$	input-output turn-on propagation time	1,1			μs
$t_{d(off)IO}$	input-output turn-off propagation time	1,4			μs
$t_{pERRRESET}$	error memory reset time	9			μs
$t_{TD}$	top / bottom switch : interlock time	3,3			μs
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)	661			A
$I_{Vs1outmax}$	output current at pin 12/14	50			mA
$I_{A0max}$	logic low output voltage	5			mA
$V_{oL}$	logic low output voltage	0,6			V
$V_{oH}$	logic high output voltage	30			V
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10\text{ V}$ )	826			A
$I_{TRIPLG}$	ground fault protection				A
$T_{tp}$	over temperature protection	110	120		°C
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9\text{ V}$ ); (option)	400			V

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